CSD19536KTT 100V N-Channel NexFET™ Power MOSFET

1 Features

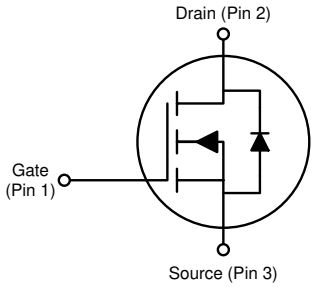
- Ultra-low Q_g and Q_{gd}
- Low thermal resistance
- Avalanche rated
- Lead-free terminal plating
- RoHS compliant
- Halogen free
- D^2PAK plastic package

2 Applications

- Secondary side synchronous rectifier
- Hot swap
- Motor control

3 Description

This 100V, 2mΩ, D^2PAK (TO-263) NexFET™ power MOSFET is designed to minimize losses in power conversion applications.



Pin Out

Product Summary

T_A = 25°C		TYPICAL VALUE		UNIT
V_{DS}	Drain-to-Source Voltage	100		V
Q_g	Gate Charge Total (10V)	118		nC
Q_{gd}	Gate Charge Gate-to-Drain	17		nC
$R_{DS(on)}$	Drain-to-Source On-Resistance	V_{GS} = 6V	2.2	mΩ
		V_{GS} = 10V	2	
$V_{GS(th)}$	Threshold Voltage	2.5		V

Device Information

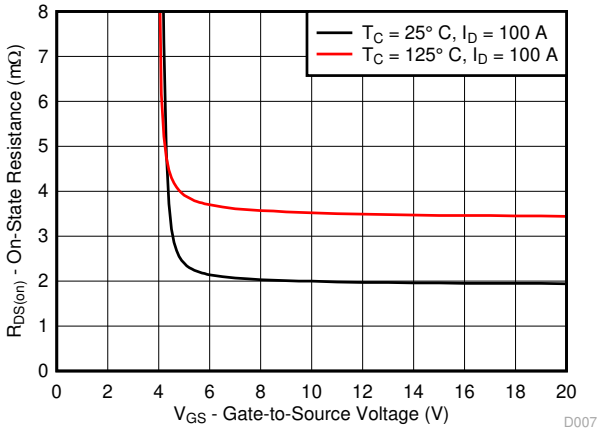
DEVICE(1)	QTY	MEDIA	PACKAGE	SHIP
CSD19536KTT	500	13-Inch Reel	D^2PAK Plastic Package	Tape and Reel
CSD19536KTTT	50			

(1) For all available packages, see the orderable addendum at the end of the data sheet.

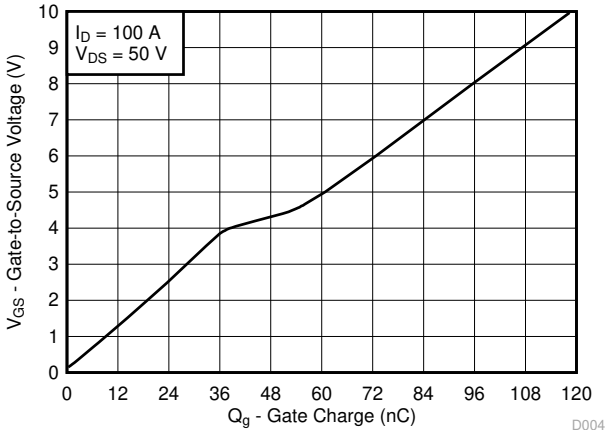
Absolute Maximum Ratings

T_A = 25°C		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	100	V
V_{GS}	Gate-to-Source Voltage	±20	V
I_D	Continuous Drain Current (Package Limited)	200	A
	Continuous Drain Current (Silicon Limited), T_C = 25°C	272	
	Continuous Drain Current (Silicon Limited), T_C = 100°C	192	
I_{DM}	Pulsed Drain Current(1)	400	A
P_D	Power Dissipation	375	W
T_J, T_{stg}	Operating Junction, Storage Temperature	–55 to 175	°C
E_{AS}	Avalanche Energy, Single Pulse I_D = 127A, L = 0.1mH, R_G = 25Ω	806	mJ

(1) Max $R_{\theta JC}$ = 0.4°C/W, Pulse duration ≤ 100µs, Duty cycle ≤ 1%.



$R_{DS(on)}$ vs V_{GS}



Gate Charge

Table of Contents

4 Specifications

4.1 Electrical Characteristics

T_A = 25°C (unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
BV_{DSS}	Drain-to-source voltage	V_{GS} = 0V, I_D = 250µA	100			V
I_{DSS}	Drain-to-source leakage current	V_{GS} = 0V, V_{DS} = 80V			1	µA
I_{GSS}	Gate-to-source leakage current	V_{DS} = 0V, V_{GS} = 20V			100	nA
$V_{GS(th)}$	Gate-to-source threshold voltage	V_{DS} = V_{GS}, I_D = 250µA	2.1	2.5	3.2	V
$R_{DS(on)}$	Drain-to-source on-resistance	V_{GS} = 6V, I_D = 100A		2.2	2.8	mΩ
		V_{GS} = 10V, I_D = 100A		2	2.4	
g_{fs}	Transconductance	V_{DS} = 10V, I_D = 100A		329		S
DYNAMIC CHARACTERISTICS						
C_{iss}	Input capacitance	V_{GS} = 0V, V_{DS} = 50V, f = 1MHz		9250	12000	pF
C_{oss}	Output capacitance			1820	2370	pF
C_{rss}	Reverse transfer capacitance			47	61	pF
R_G	Series gate resistance			1.4	2.8	Ω
Q_g	Gate charge total (10V)	V_{DS} = 50V, I_D = 100A		118	153	nC
Q_{gd}	Gate charge gate-to-drain			17		nC
Q_{gs}	Gate charge gate-to-source			37		nC
$Q_{g(th)}$	Gate charge at V_{th}			24		nC
Q_{oss}	Output charge	V_{DS} = 50V, V_{GS} = 0V		335		nC
$t_{d(on)}$	Turnon delay time	V_{DS} = 50V, V_{GS} = 10V, I_{DS} = 100A, R_G = 0Ω		13		ns
t_r	Rise time			8		ns
$t_{d(off)}$	Turnoff delay time			32		ns
t_f	Fall time			6		ns
DIODE CHARACTERISTICS						
V_{SD}	Diode forward voltage	I_{SD} = 100A, V_{GS} = 0V		0.9	1.1	V
Q_{rr}	Reverse recovery charge	V_{DS}= 50V, I_F = 100A, di/dt = 300A/µs		548		nC
t_{rr}	Reverse recovery time			103		ns

4.2 Thermal Information

T_A = 25°C (unless otherwise stated)

THERMAL METRIC		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance			0.4	°C/W
$R_{\theta JA}$	Junction-to-ambient thermal resistance			62	°C/W

4.3 Typical MOSFET Characteristics

T_A = 25°C (unless otherwise stated)

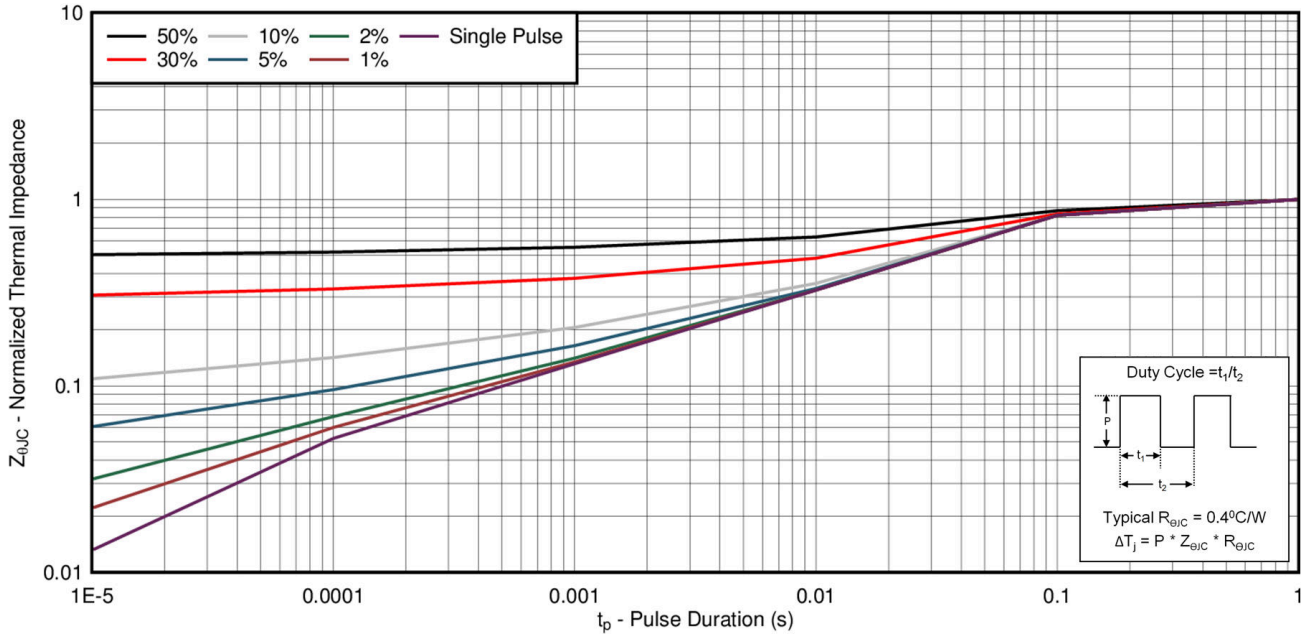


Figure 4-1. Transient Thermal Impedance

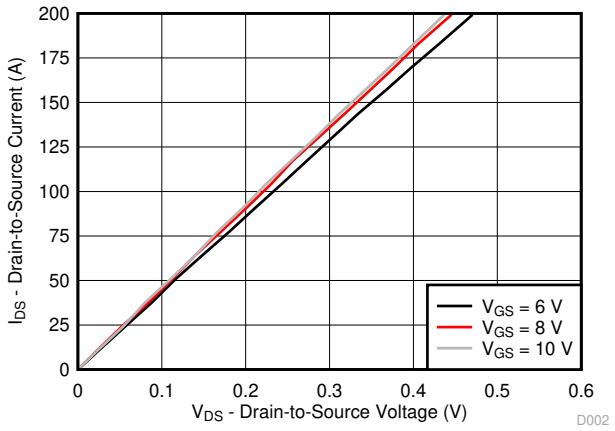
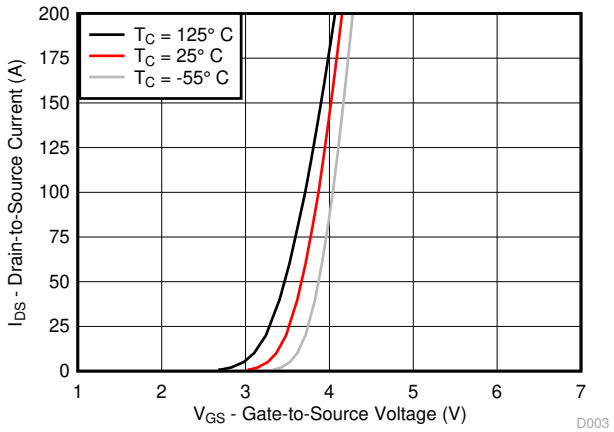
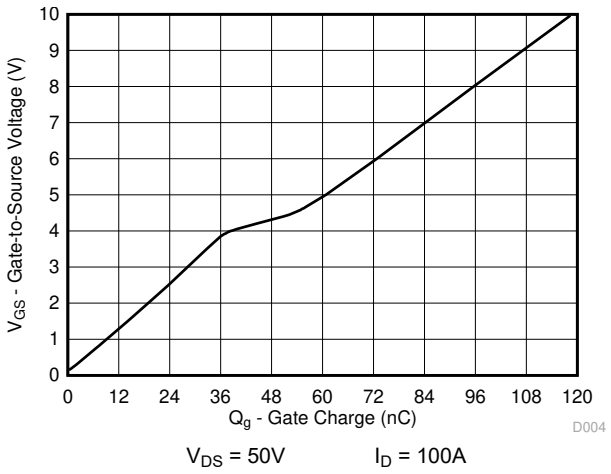


Figure 4-2. Saturation Characteristics



VDS = 5V

Figure 4-3. Transfer Characteristics



V_{DS} = 50V I_D = 100A

Figure 4-4. Gate Charge

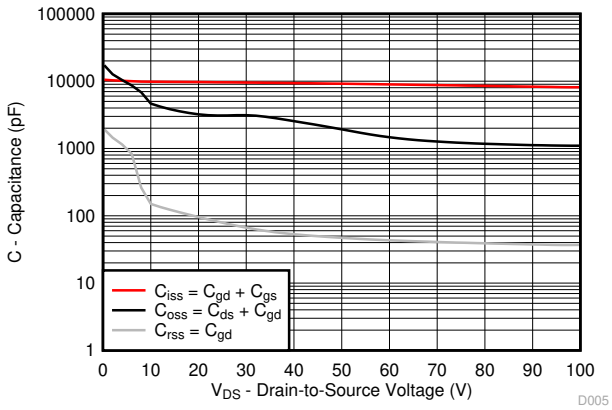
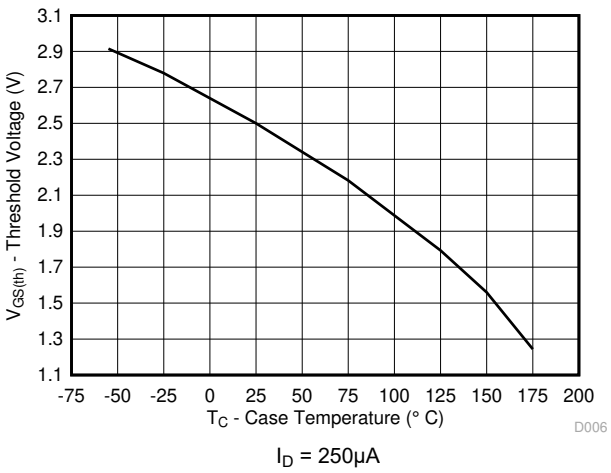


Figure 4-5. Capacitance



I_D = 250µA

Figure 4-6. Threshold Voltage vs Temperature

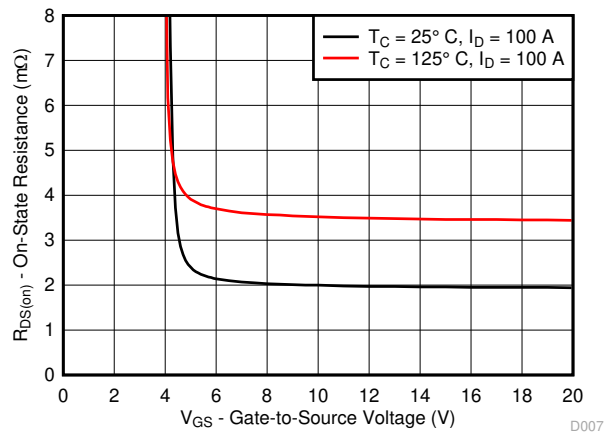
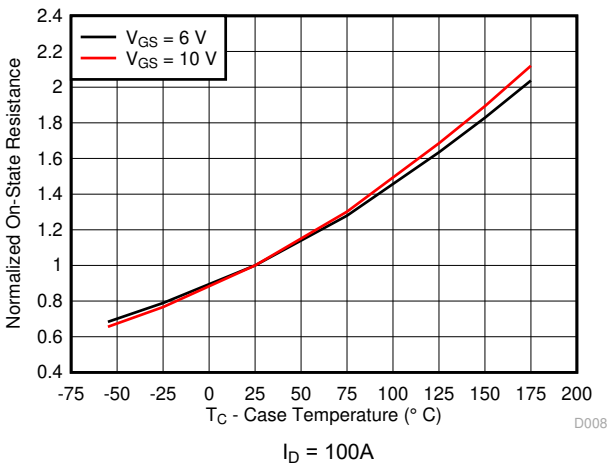


Figure 4-7. On-State Resistance vs Gate-to-Source Voltage



I_D = 100A

Figure 4-8. Normalized On-State Resistance vs Temperature

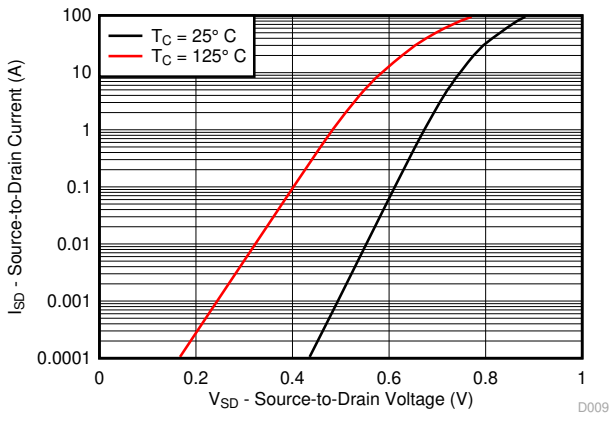
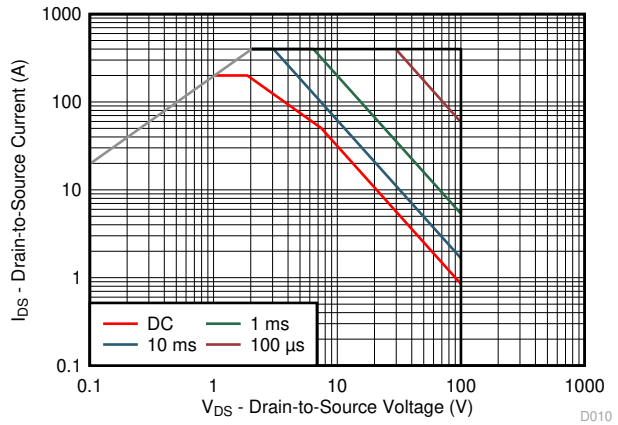


Figure 4-9. Typical Diode Forward Voltage



Single pulse, max $R_{\theta JC}$ = 0.4°C/W

Figure 4-10. Maximum Safe Operating Area

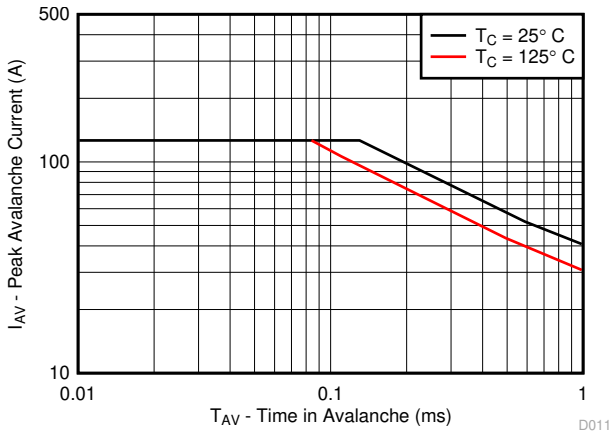


Figure 4-11. Single Pulse Unclamped Inductive Switching

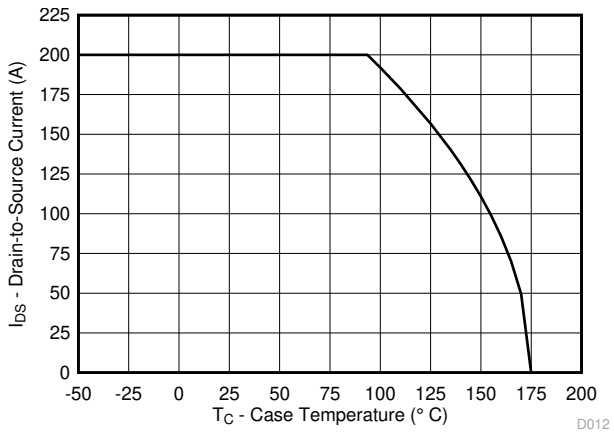


Figure 4-12. Maximum Drain Current vs Temperature

5 Device and Documentation Support

5.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

5.2 Community Resources

5.3 Trademarks

NexFET™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

6 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (May 2015) to Revision C (May 2025)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document	1

Changes from Revision A (May 2015) to Revision B (August 2016)	Page
• Added *Section 5.1* section	7

Changes from Revision * (March 2015) to Revision A (May 2015)	Page
• Added *Section 5.2* section	7
• Added PCB and stencil drawings in *Section 7*	8

7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CSD19536KTT	Active	Production	DDPAK/ TO-263 (KTT) | 2	500 | LARGE T&R	ROHS Exempt	SN	Level-2-260C-1 YEAR	-55 to 175	CSD19536KTT
CSD19536KTT.B	Active	Production	DDPAK/ TO-263 (KTT) | 2	500 | LARGE T&R	-	SN	Level-2-260C-1 YEAR	-55 to 175	CSD19536KTT
CSD19536KTTT	Active	Production	DDPAK/ TO-263 (KTT) | 2	50 | SMALL T&R	ROHS Exempt	SN	Level-2-260C-1 YEAR	-55 to 175	CSD19536KTT
CSD19536KTTT.B	Active	Production	null (null) |	50 | SMALL T&R	-	SN	Level-2-260C-1 YEAR	See CSD19536KTTT	CSD19536KTT

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

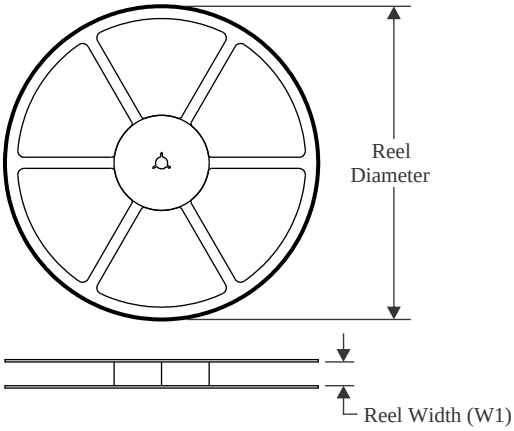
(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

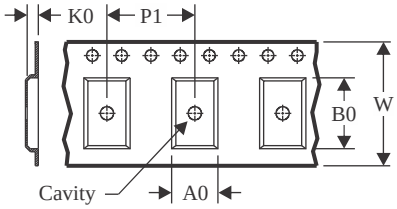
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

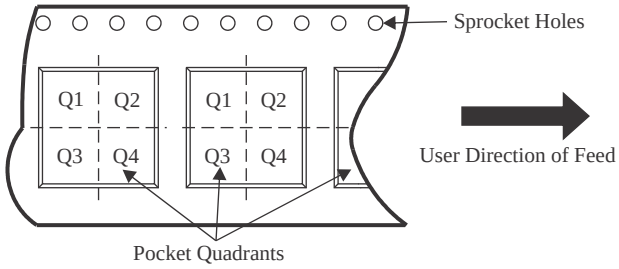


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

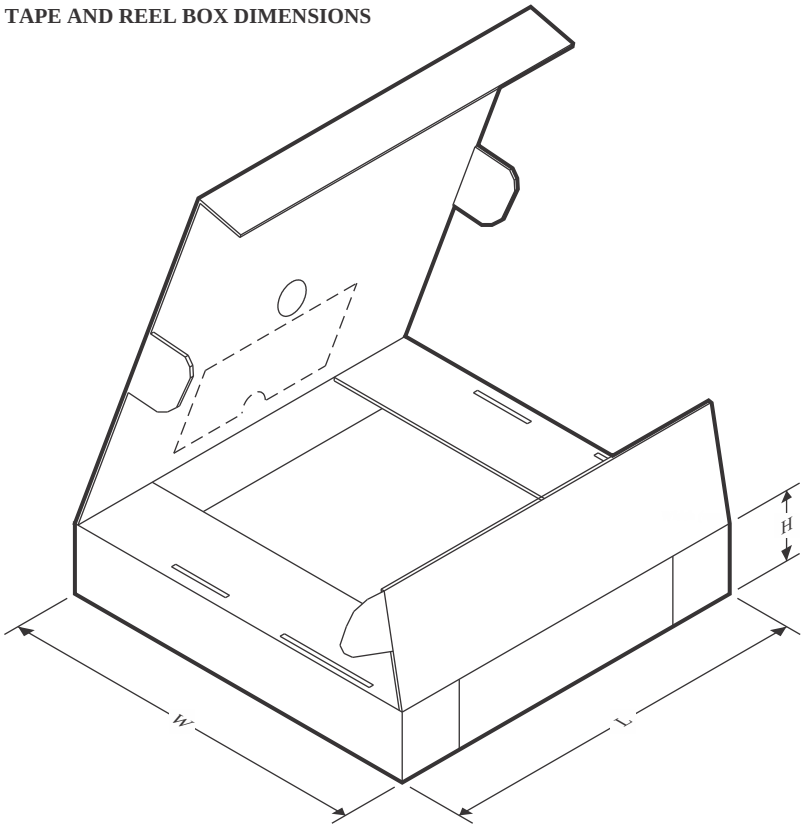
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD19536KTT	DDPAK/ TO-263	KTT	2	500	330.0	24.4	10.8	16.3	5.11	16.0	24.0	Q2
CSD19536KTTT	DDPAK/ TO-263	KTT	2	50	330.0	24.4	10.8	16.3	5.11	16.0	24.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

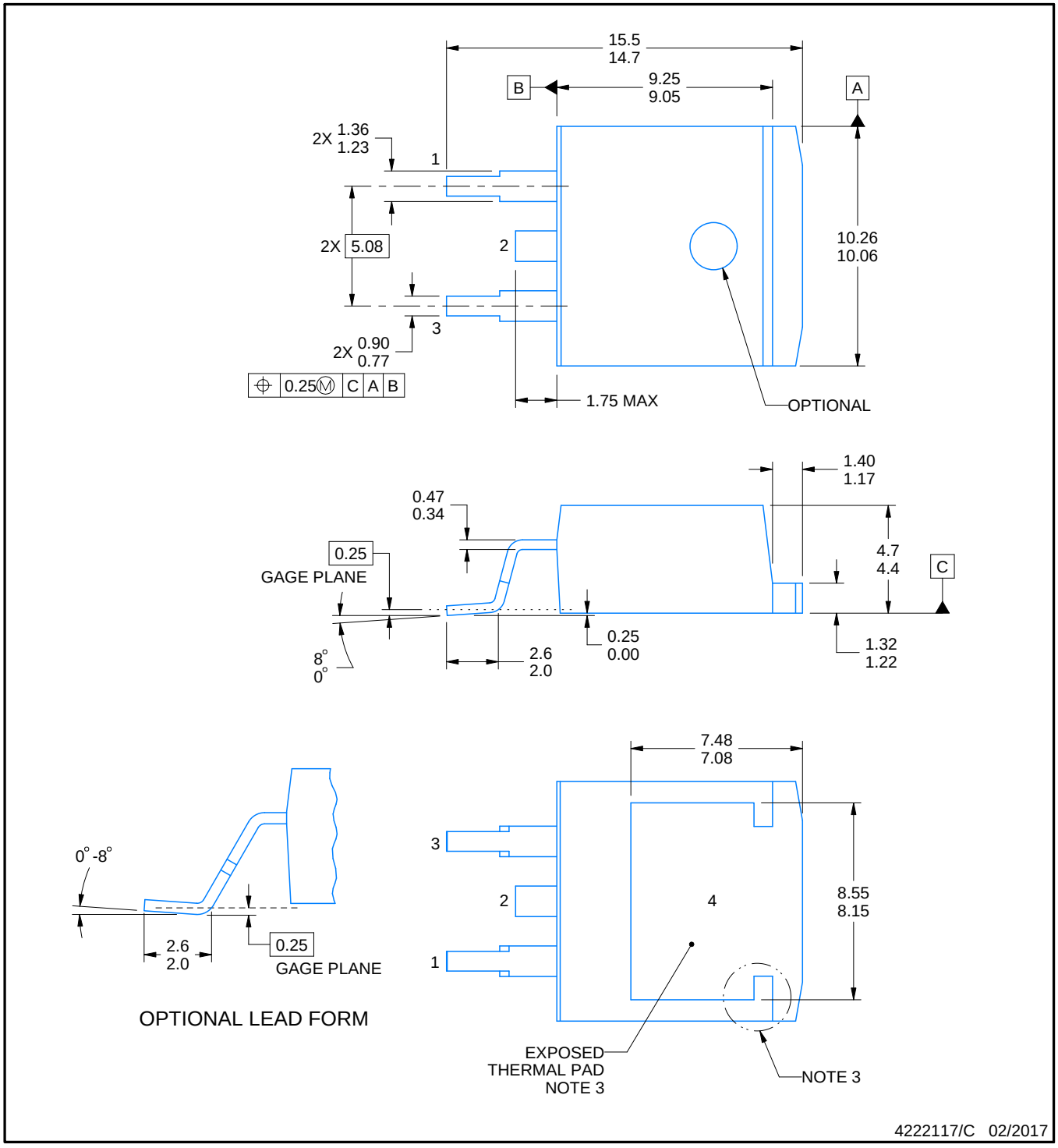
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD19536KTT	DDPAK/TO-263	KTT	2	500	340.0	340.0	38.0
CSD19536KTTT	DDPAK/TO-263	KTT	2	50	340.0	340.0	38.0

KTT0002A

PACKAGE OUTLINE

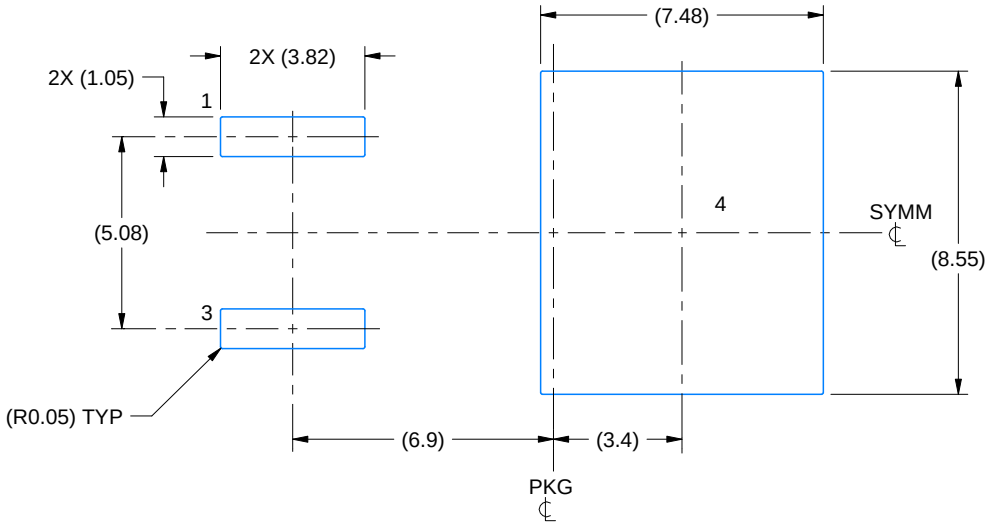
TO-263 - 4.7 mm max height

TO-263

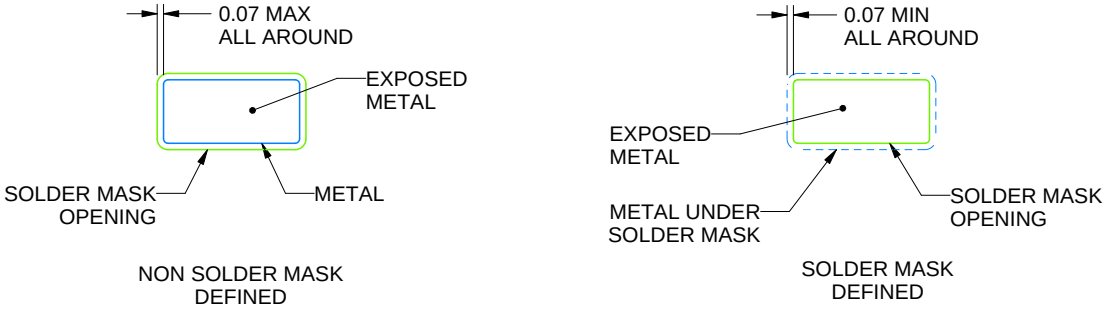


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Features may not exist and shape may vary per different assembly sites.
4. Reference JEDEC registration TO-263.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:5X

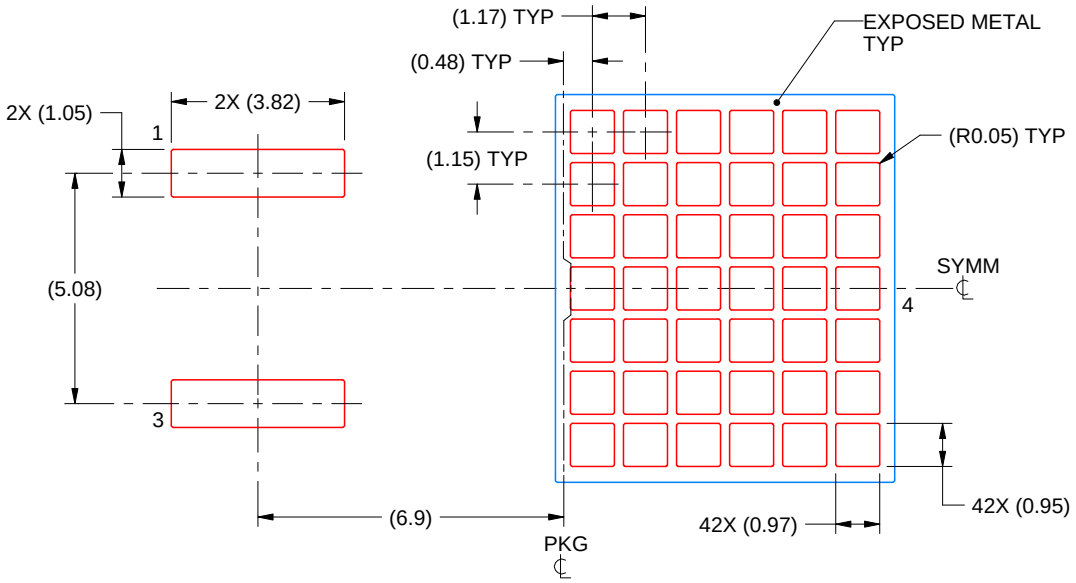


SOLDER MASK DETAILS

4222117/C 02/2017

NOTES: (continued)

5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).
6. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
60.5% PRINTED SOLDER COVERAGE BY AREA
SCALE:6X

4222117/C 02/2017

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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